

GaAs Type Hall Element

Product Information

Model: GaAs

Description:

1. Features:

* High stability type Hall element by GaAs film.

* Good linearity output voltage.

* Small size package suitable for compact application.

* Symmetrical terminal layout allows the same electrical characteristics with 180° horizontally rated application.

2. Application:

* Current sensors.

* Small brushless DC motors in industrial applications.

* Noncontacting sensors.

* Other magnetic flux sensors.

3. Electrical Characteristics:

Item	Symbol	Rank		
		A	B	C
Model: SHE-GA201T				
Hall Output Voltage	$V_H(\text{mV})$	24~33	24~33	24~33
Offset Voltage Ratio	$V_0/V_H(\%)$	$0\sim\pm 5$	$\pm 5\sim\pm 10$	$\pm 10\sim\pm 15$
Input Resistance	$R_{in}(\Omega)$	650~1000	650~	650~1000
Output Resistance	$R_{out}(\Omega)$	3000max	3000max	3000max
Model: SHE-GA202T				
Hall Output Voltage	$V_H(\text{mV})$	24~34	24~34	24~34
Offset Voltage Ratio	$V_0/V_H(\%)$	$0\sim\pm 5$	$\pm 5\sim\pm 10$	$\pm 10\sim\pm 15$
Input Resistance	$R_{in}(\Omega)$	500~900	500~900	500~900
Output Resistance	$R_{out}(\Omega)$	1200~2200	1200~2200	1200~2200

Model: SHE-GA201T				
Hall Output Voltage	$V_H(\text{mV})$	17~23	17~23	17~23
Offset Voltage Ratio	$V_0/V_H(\%)$	$0 \sim \pm 5$	$\pm 5 \sim \pm 10$	$\pm 10 \sim \pm 15$
Input Resistance	$R_{in}(\Omega)$	400~600	400~600	400~600
Output Resistance	$R_{out}(\Omega)$	400~600	400~600	400~600

4. Conditions

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Hall Output Voltage	V_H ※1	$V_c=1\text{V}$ $B=1000\text{G}(100\text{mT})$	—	—	—	mV
Offset Voltage Ratio	V_0/V_H	$V_c=1\text{V}$ $B=0\text{G}(0\text{mT})$	—	—	—	%
Input Resistance	R_{in}	$I_c=1\text{mA}$ $B=0\text{G}(0\text{mT})$	—	—	—	Ω
Output Resistance	R_{out}	$I_c=1\text{mA}$ $B=0\text{G}(0\text{mT})$	—	—	—	Ω
Hall Output Voltage Temperature Coefficient	αV_H ※2	$I_c=5\text{mA}$ $B=1000\text{G}(100\text{mT})$ $T_1=25^\circ\text{C}$ $T_2=125^\circ\text{C}$	—	— 0.06	—	%/ $^\circ\text{C}$
Input Resistance Temperature Coefficient	$\beta \cdot R_i$	$I_c=1\text{mA}$ $B=0\text{G}(0\text{mT})$ $T_1=25^\circ\text{C}$ $T_2=125^\circ\text{C}$	—	0.3	—	%/ $^\circ\text{C}$
Linearity	γ ※4	$I_c=5\text{mA}, B_1=1\text{kG}$	—	—	2	%

		B2=5kG				
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Vc: Power Voltage; Ic: Power Current; B: Flux Density

※1: $V_H = V_{HM} - V_O$; V_{HM} : Output Voltage

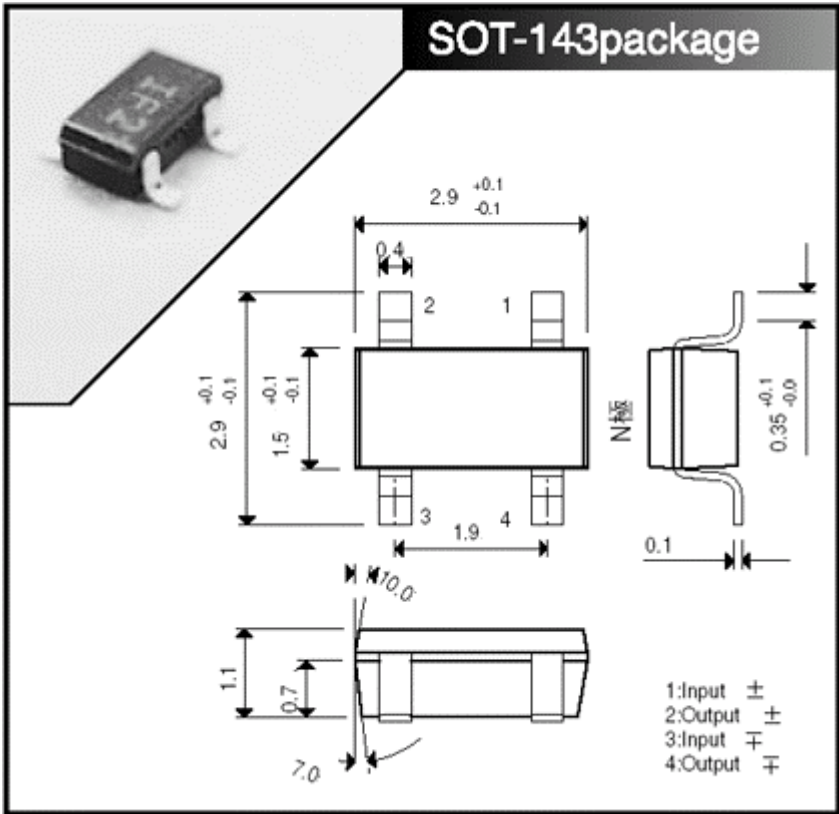
※2: $\alpha V_H = [1/V_H(T1)] \times [V_H(T1) - V_H(T2)] \times [1/(T1 - T2)] \times 100$

※3: $\beta - Ri = [1/Rin(T1)] \times [Rin(T1) - Rin(T2)] \times [1/(T1 - T2)] \times 100$

※4: $\gamma = (K_{H2} - K_{H1}) / [(K_{H1} + K_{H2}) / 2] \times 100$
 $K_{H1} = V_H(B1) / (Ic \times B1)$;
 $K_{H2} = V_H(B2) / (Ic \times B2)$

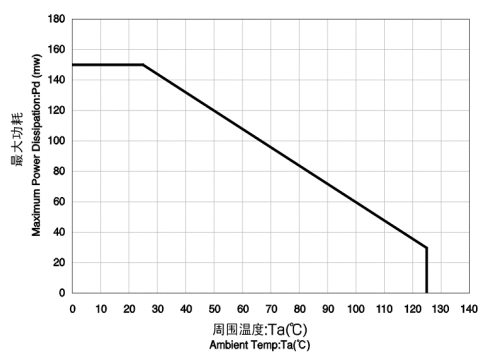
5. Absolute Maximum Ratings

Item	Symbol	Limit	Unit
Max. Input Current	Ic max	15(at25℃)	mA
Power Dissipation	Pd	150	mW
Operating Temp. Range	Topr	-40~125	℃
Storage Temp. Range	Tstg	-50~150	℃

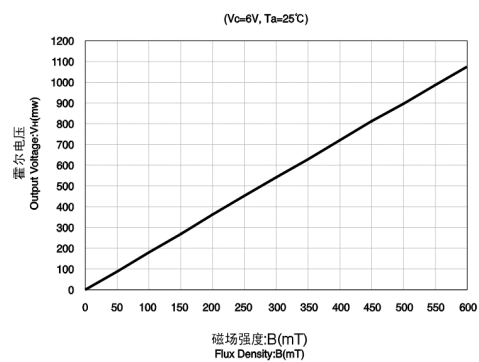


特性曲线图 Characteristic Curve

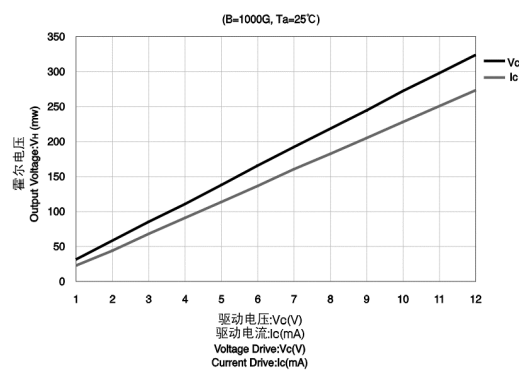
Pd-Ta



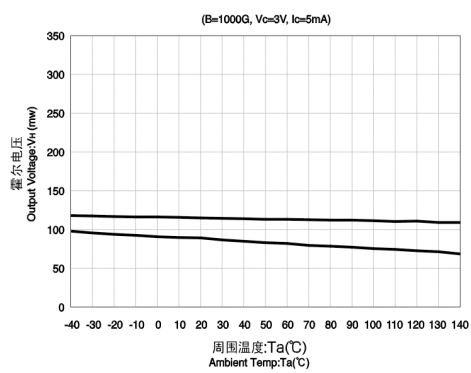
VH-B



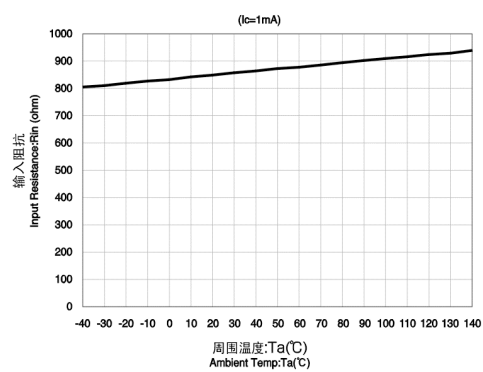
VH-Vc



VH-Ta



Rin-Ta



Rout-Ta

